

### INCHANGE SEMICONDUCTOR

## **Isc N-Channel MOSFET Transistor**

## STF10NM65N

#### FEATURES

- With TO-220F package
- · Low input capacitance and gate charge
- · Low gate input resistance
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation
- APPLICATIONS
- Switching applications
- · Load switch
- Power management

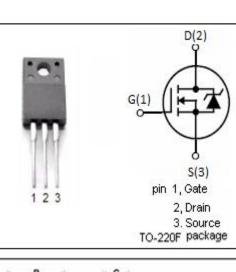
#### ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

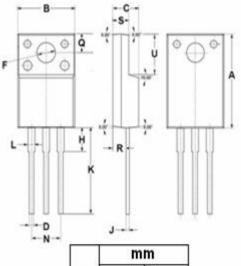
SYMBOL	PARAMETER	VALUE	UNIT
V <sub>DSS</sub>	Drain-Source Voltage	650	V
$V_{GSS}$	Gate-Source Voltage	±25	V
ID	Drain Current-ContinuousTc=25°C9Tc=100°C5.7		A
I <sub>DM</sub>	Drain Current-Single Pulsed	36	A
P <sub>D</sub>	Total Dissipation @T <sub>C</sub> =25°C	25	W
Tj	Max. Operating Junction Temperature	150	°C
T <sub>stg</sub>	Storage Temperature	-55~150	°C

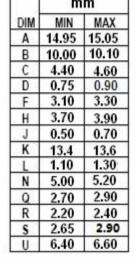
#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	МАХ	UNIT
Rth(ch-c)	Channel-to-case thermal resistance	5	°C <b>/W</b>
Rth(ch-a)	Channel-to-ambient thermal resistance	62.5	°C <b>/W</b>

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### **ELECTRICAL CHARACTERISTICS**

#### $T_{\text{C}}\text{=}25^{\circ}\!\!\!\!\mathrm{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	МАХ	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> = 1mA	650			V
V <sub>GS</sub> (th)	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> ; I <sub>D</sub> =0.25mA	2.0		4.0	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> =4.5A		0.43	0.48	Ω
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> = ±20V;V <sub>DS</sub> =0V			±0.1	μA
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> =650V; V <sub>GS</sub> = 0V;Tc=25℃ Tc=125℃			1 100	μA
V <sub>SDF</sub>	Diode forward voltage	I <sub>SD</sub> =9A, V <sub>GS</sub> = 0 V			1.3	v

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